



Features

- 3D NAND Flash for higher durability and capacity
- SLC caching: enhances transmission speed
- Wide capacity range: 512GB to 2TB
- PCle Gen 4 x 4 interface
- Support NVMe 1.4
- NANDXtend™ ECC Technology
- Support SMART and TRIM commands

Ordering Information

Capacity	Part Number	EAN Code
512GB	AGI512GG44AI818	4718009612037
1TB	AGI1T0G44AI818	4718009612020
1TB	AGI1T0G43AI818	4718009612143
2TB	AGI2T0G43AI818	4718009612150















Specifications

Capacity: 512GB / 1TB / 2TB
NAND Flash: 3D NAND
Interface: PCle Gen 4 x 4
Form factor: M.2 2280
MTBF: 1,600,000 hours

• Operating Voltage: 3.3V±5%

Humidity: 5% to~98%RH (Non-condensing)
Operating Vibration:15G(7 to 2000Hz)
Certifications: CE, FCC, BSMI, RoHS

• Warranty: 3 years

• Dimensions (L x W x H):

80 x 22 x 5.4 mm (with heat sink)

80 x 22 x 2.1 mm (without heat sink)

• Weight: 7.5g±0.2g

512GB : 12g (w/ heat sink) / 6.3g(w/o heat sink)

1TB: 11.2g (w/ heat sink) / 5.2g(w/o heat sink)

Operating temperature: 0°C-70°C
Storage temperature: -40°C-85°C
Shock resistance: 1500G/0.5ms

Performance

Capacity	CDM-SEQ1M Q8T1		
	Seq. Read (MB/s)	Seq. Write (MB/s)	TBW
512GB(44)	5000	2600	300TB
1TB(44)	5000	4500	600TB
1TB(43)	4700	2800	600TB
2TB(43)	5200	4700	1200TB

^{*}Performance may vary based on SSD capacity, hardware test platform, test software, operating system, and other system variables

Schematics

